

LCP02-150B1

COMPLIES WITH FOLLOWING STANDARDS

	Peak surge voltage (V)	Voltage waveform (μs)	Required peak current (A)	Current waveform (μs)	Minimum serial resistor to meet standard (Ω)
ITU-T K20	4000 1000	10/700 10/700	100 25	5/310 5/310	50 0
ITU-T K21	4000 1500	10/700 10/700	100 37.5	5/310 5/310	50 0
VDE0433	2000	10/700	50	5/310	5
VDE0878	2000	1.2/50	50	1/20	0
IEC61000-4-5	level 3 level 4	10/700 1.2/50	50 100	5/310 8/20	5 25
FCC Part 68 lightning surge type A	1500 800	10/160 10/560	200 100	10/160 10/560	20 15
FCC Part 68 lightning surge type B	1000	9/720	25	5/320	0
BELLCORE GR-1089-CORE First level	2500 1000	2/10 10/1000	500 100	2/10 10/1000	20 25
BELLCORE GR-1089-CORE Second level	5000	2/10	500	2/10	40
BELLCORE GR-1089-CORE Intrabuilding	800 1500	2/10 2/10	100 100	2/10 2/10	0 0

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C)

Symbol	Parameter		Value	Unit
I _{PP}	Peak pulse current	10/1000μs 5/310μs 1/20μs	30 45 65	A
I _{TSM}	Non repetitive surge peak on-state current (F = 50Hz)	t _p = 0.2 s t _p = 1 s t _p = 15 min	5.5 4.2 1.5	A
V _{GN} max V _{GP} max Δ V _{bat} max	Maximum negative battery voltage range Maximum positive battery voltage range Total battery supply voltage	See fig.1	-110 to 0 0 to +95 190	V
T _{op}	Operating temperature range (see note 1)		-20 to +85	°C
T _{stg}	Storage temperature range		- 55 to + 150	°C
T _L	Lead solder temperature (10s duration)		260	°C

Note 1: Within the T_{op} range, the LCP02-150B1 keeps on operating. The impacts of the ambient temperature are given by derating curves.

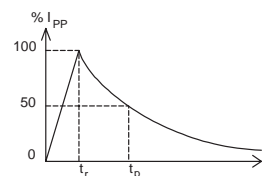
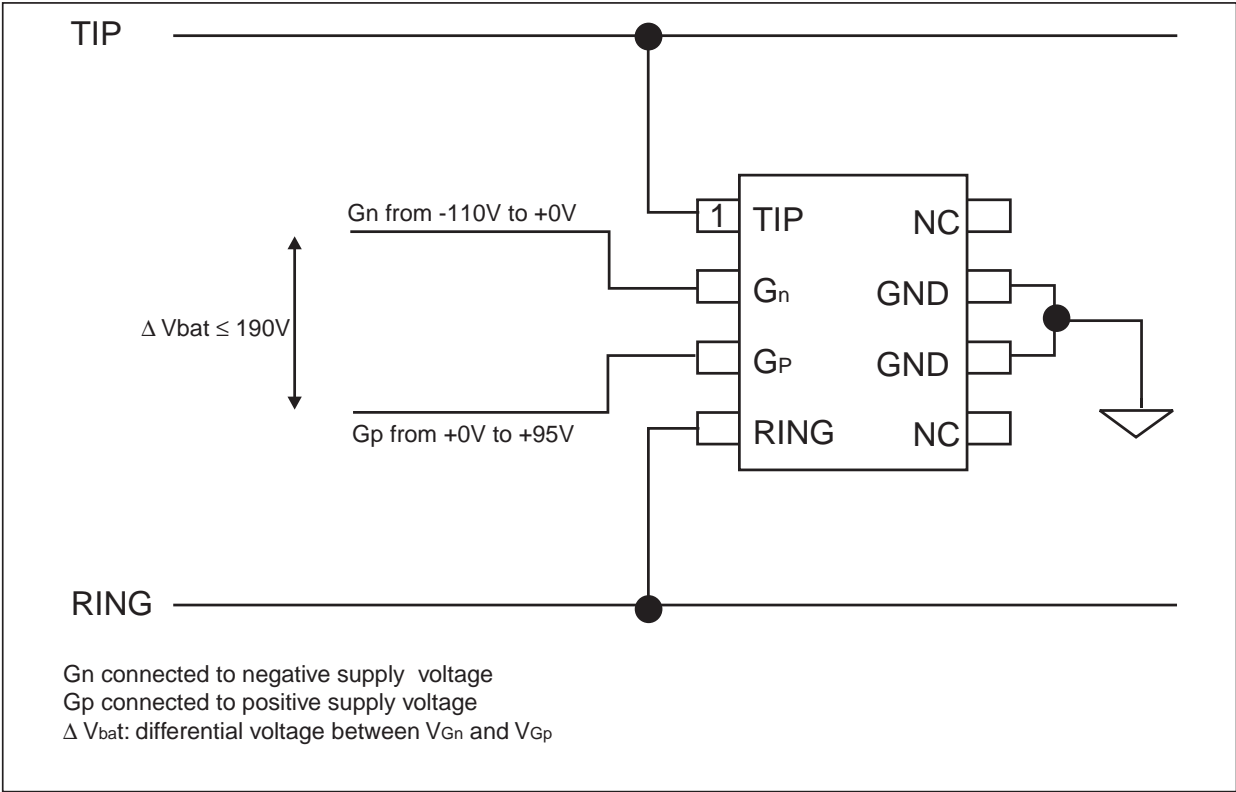


Fig. 1: Test circuit



THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j-a)}	Junction to ambient	150	°C/W

LCP02-150B1

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$)

1 - PARAMETERS RELATED TO THE NEGATIVE SUPPRESSOR

Symbol	Parameter	Test conditions	Min.	Max.	Unit
I_{Gn}	Negative gate trigger current	$V_{Gn/GND} = -60\text{V}$ Measured at 50Hz		5	mA
I_{H-}	Holding current (see fig.2)	Go-No Go test, $V_{Gn} = -60\text{V}$	150		mA
I_{RGL-}	Reverse leakage current Gn/Line	$T_j = 25^{\circ}\text{C}$, $V_{Gn/line} = -190\text{V}$		5	μA
V_{DGL-}	Dynamic switching voltage Gn / Line (see note 2)	$V_{Gn/GND} = -60\text{V}$ 10/1000 μs 1kV $R_P = 25\Omega$ $I_{PP} = 30\text{A}$ 10/700 μs 2kV $R_P = 25\Omega$ $I_{PP} = 30\text{A}$ 1.2/50 μs 2kV $R_P = 25\Omega$ $I_{PP} = 30\text{A}$		18 8 15	V

2 - PARAMETERS RELATED TO THE POSITIVE SUPPRESSOR

Symbol	Parameter	Test conditions	Min.	Max.	Unit
I_{Gp}	Positive gate trigger current	$V_{Gp/GND} = 60\text{V}$ Measured at 50Hz		5	mA
I_{RGL+}	Reverse leakage current Gp/LINE	$T_j = 25^{\circ}\text{C}$, $V_{Gp/line} = +190\text{V}$		5	μA
V_{DGL+}	Dynamic switching voltage Gp / Line (see note 2)	$V_{Gp/GND} = +60\text{V}$ 10/1000 μs 1kV $R_P = 25\Omega$ $I_{PP} = 30\text{A}$ 10/700 μs 2kV $R_P = 25\Omega$ $I_{PP} = 30\text{A}$ 1.2/50 μs 2kV $R_P = 25\Omega$ $I_{PP} = 30\text{A}$		18 8 35	V

3 - PARAMETERS RELATED TO LINE/GND

Symbol	Parameter	Test conditions	Typ.	Max.	Unit
I_R	Reverse leakage current	$T_j = 25^{\circ}\text{C}$, $V_{LINE} = +90\text{V}$, $V_{GP/LINE} = +1\text{V}$ $T_j = 25^{\circ}\text{C}$, $V_{LINE} = -105\text{V}$, $V_{GN/LINE} = -1\text{V}$		5 5	μA
C_{off}	Capacitance LINE/GND	$V_R = -3\text{V}$, $F = 1\text{MHz}$, $V_{Gp} = 60\text{V}$, $V_{Gn} = -60\text{V}$	60		pF

Note 2: The V_{DGL} value is the difference between the peak line voltage during the surge and the programmed gate voltage.

Fig. 2: Relative variation of holding current versus junction temperature.

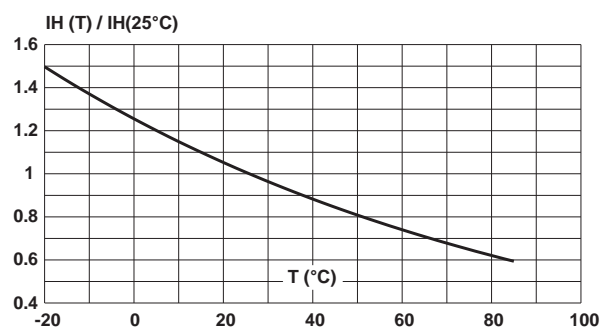


Fig. 3: Maximum non repetitive surge peak on state current versus overload duration (with 50Hz sinusoidal wave and initial junction temperature equal to $+25^\circ\text{C}$).

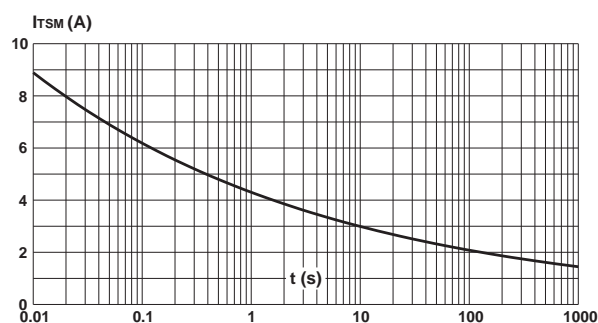
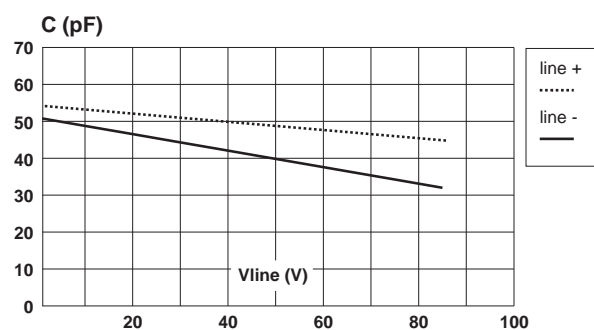


Fig. 4: Capacitance versus reverse applied voltage (typical values) with $V_{GN} = -90\text{V}$ and $V_{GP} = +90\text{V}$.



[illegible]

The series resistors Rs1 and Rs2 designed in figure 5 represent the fuse resistors or the PTCs which are needed to withstand the power contact or the power induction tests imposed by the country standards. Taking this factor into account, the actual lightning surge current flowing through the LCP02-150B1 is equal to :

$$I_{\text{surge}} = V_{\text{surge}} / (R_g + R_s)$$

R_s = series resistor of the line card (e.g. PTC)

I surge = $1000 / (10 + 50) = \underline{17A}$

The LCP02-150B1 topology is particularly optimized for the new telecom applications such as fiber in the loop, WLL systems, decentralized central office for example. The schematics of figures 6 and 7 give the 2 most frequent topologies used for these emergent applications

Fig. 6: Protection of SLIC with positive and negative battery voltages.

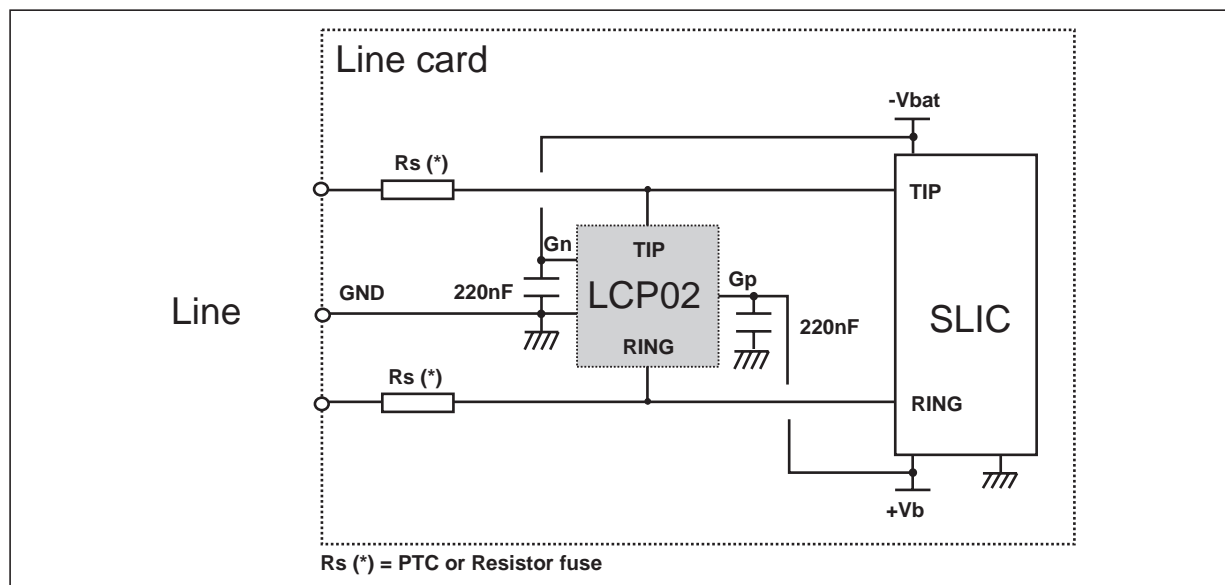


Fig. 7: Protection of high voltage SLIC

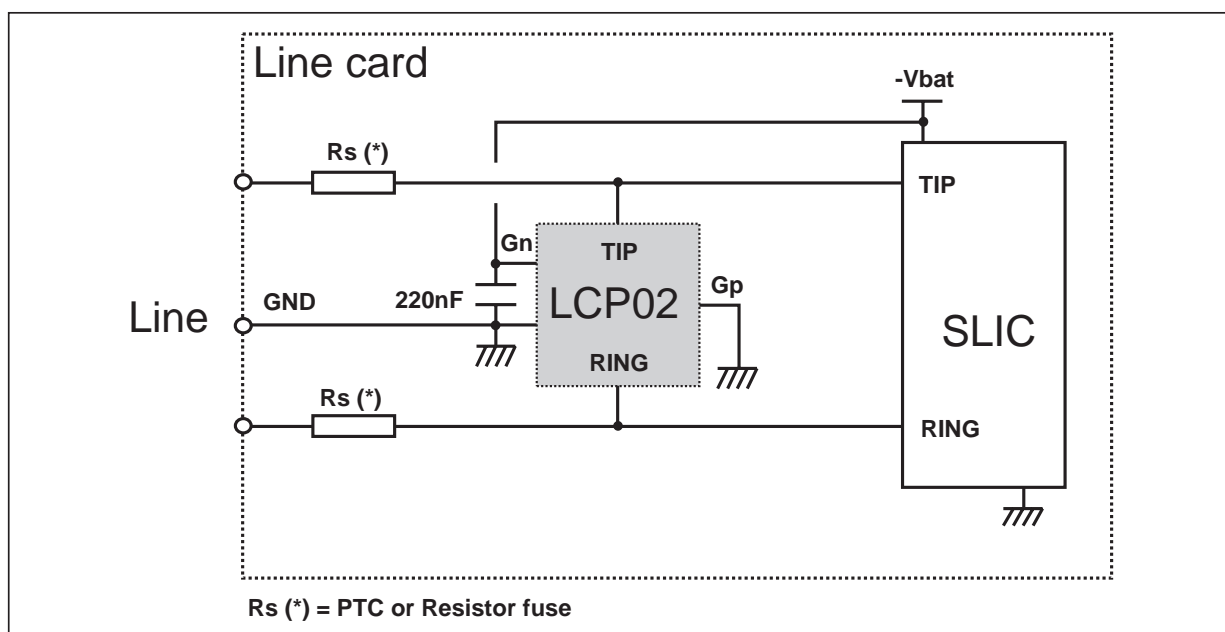


Figure 6 shows the classical protection topology for SLIC using both positive and negative battery voltages. With such a protection the SLIC is protected against surge over $+V_b$ and lower than $-V_{bat}$. In this case, $+V_b$ can be programmed up to $+95V$ while $-V_{bat}$ can be programmed down to $-110V$. Please note that the differential voltage does not exceed ΔV_{bat} max at $190V$.

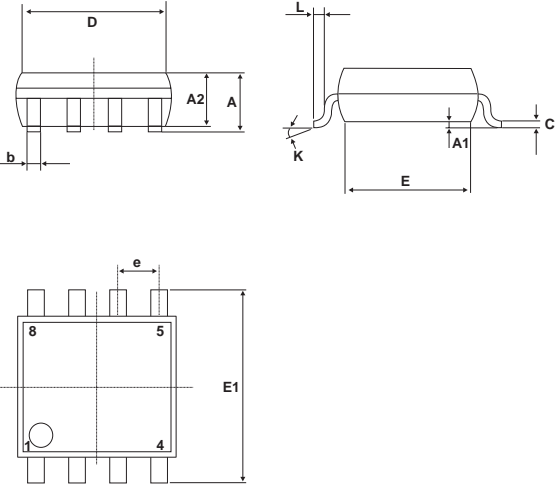
Figure 7 gives the protection topology for the new SLIC using high negative voltage down to $-110V$.

LCP02-150B1

PACKAGE MECHANICAL DATA

SO-8 Wide Plastic

REF.	DIMENSIONS					
	Millimetres			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			2.50			0.099
A1			0.25			0.010
A2	1.51		2.00	0.059		0.079
b	0.35	0.40	0.51	0.013	0.016	0.020
c	0.10	0.20	0.35	0.003	0.008	0.014
D			6.05			0.239
E	5.02		6.22	0.197		0.245
E1	7.62		8.89	0.30		0.35
e		1.27			0.05	
K	10°					
L	0.50		0.80	0.019		0.032



ORDER CODE

Ordering Type	Marking	Package	Weight	Base qty	Delivery mode
LCP02-150B1	LCP02	SO-8-Wide	0.13g	90	Tube
LCP02-150B1RL				1500	Tape & Reel

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